

SEMICONDUCTOR

BCV72

NPN General Purpose Amplifier

- This device is designed for general purpose applications at collector currents to 300mA.
- Sourced from process 10.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings * T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
√ _{CEO}	Collector-Emitter Voltage	60	V
V _{CBO}	Collector-Base Voltage	80	V
V _{EBO}	Emitter-Base Voltage	5.0	V
I _C	Collector current (DC) 500		mA
T _J , T _{sta}	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charact	eristics	•	•	•	•
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 10 \mu {\rm A}, I_{\rm E} = 0$	80		V
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 2mA, I_{\rm B} = 0$	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10\mu A, I_{\rm C} = 0$	5.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 20V, I_E = 0$		100	nA
		$V_{CB} = 20V, I_E = 0, T_a = 100^{\circ}C$		10	μA
On Charact	eristics				
h _{FE}	DC Current Gain	$I_{C} = 2.0 \text{mA}, V_{CE} = 5.0 \text{V}$	200	450	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0.5 {\rm mA}$		0.25	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 2.0mA, V _{CE} = 5.0V	0.55	0.7	V

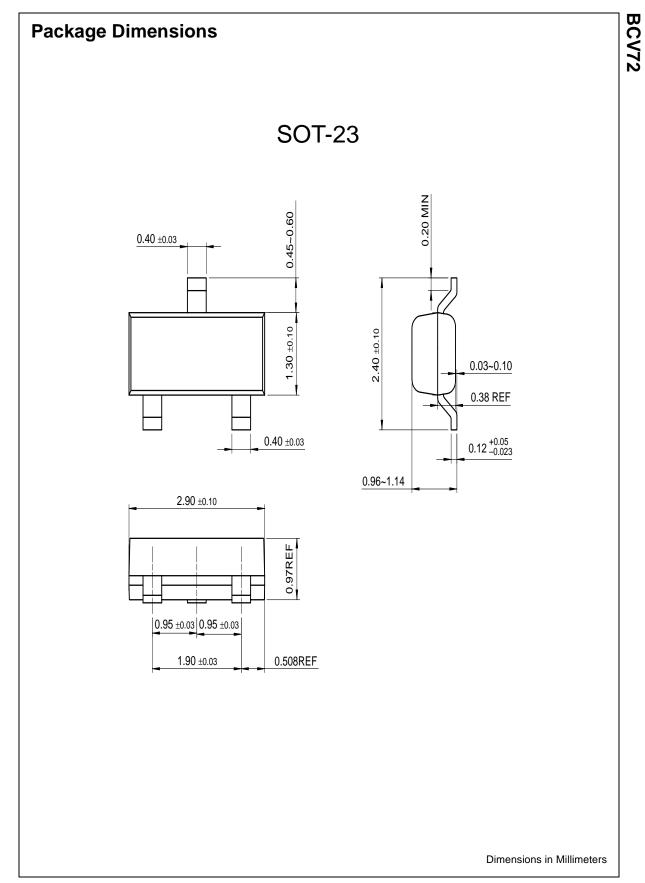
Thermal Characteristics ${\rm T}_a{=}25^{\circ}{\rm C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
PD	Total Device Dissipation	350	mW
-	Derate above 25°C	2.8	mW/°C
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	357	°C/W

Device mounted on FR-4PCB 40mm × 40mm × 1.5mm

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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